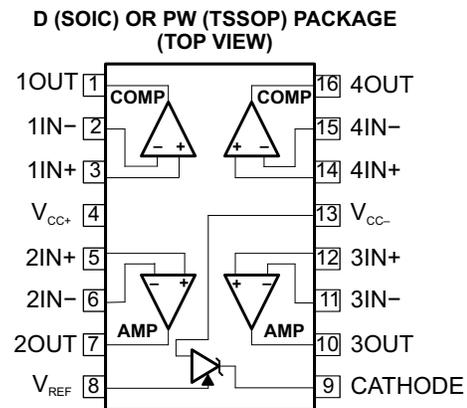


FEATURES

- **OPERATIONAL AMPLIFIERS**
 - Low Supply Current...200 μ A/A
 - Medium Speed...2.1 MHz
 - Low-Level Output Voltage Close to V_{CC} ...0.1 V Typ ($R_L = 10\text{ k}\Omega$)
 - Input Common-Mode Voltage Range Includes Ground
- **COMPARATORS**
 - Low Supply Current...200 μ A/A ($V_{CC} = 5\text{ V}$)
 - Input Common-Mode Voltage Range Includes Ground
 - Low Output Saturation Voltage... Typically 250 mV ($I_{\text{sink}} = 4\text{ mA}$)
- **VOLTAGE REFERENCE**
 - Adjustable Output Voltage... V_{REF} to 36 V
 - Sink Current Capability...1 mA to 100 mA
 - 0.4% (A Grade) and 1% (Standard Grade) Precision
 - Latch-Up Immunity

APPLICATIONS

- Switch-Mode Power Supplies
- Battery Chargers
- Voltage and Current Sensing
- Power-Good, Overvoltage, Undervoltage, Overcurrent Detection
- Window Comparators
- Alarms, Detectors, and Sensors



DESCRIPTION/ORDERING INFORMATION

The TSM102 and TSM102A combine the building blocks of a dual operational amplifier, a dual comparator, and a precision voltage reference, all of which often are used to implement a wide variety of power-management functions, including overcurrent detection, undervoltage/overvoltage detection, power-good detection, window comparators, error amplifiers, etc. Additional applications include alarm and detector/sensor applications.

The TSM102A offers a tight V_{REF} tolerance of 0.4% at 25°C. The TSM102 and TSM102A are characterized for operation from –40°C to 85°C.

ORDERING INFORMATION

| T_A | MAX V_{REF} TOLERANCE (25°C) | PACKAGE ⁽¹⁾ | | ORDERABLE PART NUMBER | TOP-SIDE MARKING |
|---------------|---------------------------------------|------------------------|--------------|-----------------------|------------------|
| –40°C to 85°C | A grade: 0.4% precision | SOIC – D | Tube of 75 | TSM102AID | TSM102AI |
| | | | Reel of 2500 | TSM102AIDR | |
| | | TSSOP – PW | Tube of 90 | TSM102AIPW | SN102AI |
| | | | Reel of 2000 | TSM102AIPWR | |
| | Standard grade: 1% precision | SOIC – D | Tube of 75 | TSM102ID | TSM102I |
| | | | Reel of 2500 | TSM102IDR | |
| TSSOP – PW | | Tube of 90 | TSM102IPW | SN102I | |
| | | Reel of 2000 | TSM102IPWR | | |

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

TSM102, TSM102A DUAL OPERATIONAL AMPLIFIER, DUAL COMPARATOR, AND VOLTAGE REFERENCE

SLVS602–MARCH 2006

Absolute Maximum Ratings⁽¹⁾

over free-air temperature range (unless otherwise noted)

| | | MIN | MAX | UNIT |
|---------------|---|------------|-----|------|
| V_{CC} | Supply voltage | | 36 | V |
| V_{ID} | Input differential voltage | | 36 | V |
| V_I | Input voltage range | -0.3 | 36 | V |
| I_{KA} | Voltage reference cathode current | | 100 | mA |
| θ_{JA} | Package thermal impedance ⁽²⁾⁽³⁾ | D package | | 73 |
| | | PW package | | 108 |
| T_J | Maximum junction temperature | | 150 | °C |
| T_{stg} | Storage temperature range | -65 | 150 | °C |

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) Maximum power dissipation is a function of $T_J(\max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(\max) - T_A)/\theta_{JA}$. Selecting the maximum of 150°C can affect reliability.
- (3) The package thermal impedance is calculated in accordance with JESD 51-7.

Recommended Operating Conditions

| | | MIN | MAX | UNIT |
|---------------------|---------------------------------------|-----------|---------------------|------|
| $V_{CC+} - V_{CC-}$ | Supply voltage | 3 | 30 | V |
| V_{ID} | Comparator differential input voltage | | $V_{CC+} - V_{CC-}$ | V |
| V_{KA} | Cathode-to-anode voltage | V_{REF} | 36 | V |
| I_K | Reference cathode current | 1 | 100 | mA |
| T_A | Operating free-air temperature | -40 | 85 | °C |

Total Device Electrical Characteristics

| PARAMETER | | TEST CONDITIONS | T_A | MIN | TYP | MAX | UNIT |
|-----------|---|---|------------|-----|-----|-----|------|
| I_{CC} | Total supply current, excluding reference cathode current | $V_{CC+} = 5\text{ V}$, $V_{CC-} = 0\text{ V}$, No load | 25°C | | 0.8 | 1.5 | mA |
| | | | Full range | | | 2 | |

Operational Amplifier Electrical Characteristics
 $V_{CC+} = 5\text{ V}$, $V_{CC-} = \text{GND}$, R_1 connected to $V_{CC+}/2$ (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | T_A | MIN | TYP | MAX | UNIT |
|-----------------|--------------------------------|---|------------|-----------|------|-----------------|------------------------------|
| V_{IO} | Input offset voltage | | 25°C | | 1 | 4.5 | mV |
| | | | Full range | | | 6.5 | |
| αV_{IO} | Input offset voltage drift | | 25°C | | 10 | | $\mu\text{V}/^\circ\text{C}$ |
| I_{IO} | Input offset current | | 25°C | | 5 | 20 | nA |
| | | | Full range | | | 40 | |
| I_{IB} | Input bias current | | 25°C | | 20 | 100 | nA |
| | | | Full range | | | 200 | |
| A_{VD} | Large-signal voltage gain | $V_{CC+} = 30\text{ V}$, $R_1 = 10\text{ k}\Omega$, $V_O = 5\text{ V to }25\text{ V}$ | 25°C | 50 | 100 | | V/mV |
| | | | Full range | | 25 | | |
| k_{SVR} | Supply-voltage rejection ratio | $V_{CC+} = 5\text{ V to }30\text{ V}$ | 25°C | 80 | 100 | | dB |
| V_{ICM} | Input common-mode voltage | | 25°C | V_{CC-} | | $V_{CC+} - 1.8$ | V |
| | | | Full range | V_{CC-} | | $V_{CC+} - 2.2$ | |
| CMRR | Common-mode rejection ratio | $V_{CC+} = 30\text{ V}$, $V_{ICM} = 0\text{ V to }V_{CC+} - 1.8\text{ V}$ | 25°C | 70 | 90 | | dB |
| I_{SC} | Short-circuit current | $V_{ID} = \pm 1\text{ V}$, $V_O = 2.5\text{ V}$ | 25°C | Source | 3 | 6 | mA |
| | | | | Sink | 3 | 6 | |
| V_{OH} | High-level output voltage | $V_{CC+} = 30\text{ V}$, $R_L = 10\text{ k}\Omega$ | 25°C | 27 | 28 | | V |
| | | | Full range | | 26 | | |
| V_{OL} | Low-level output voltage | $R_L = 10\text{ k}\Omega$ | 25°C | | 130 | 170 | mV |
| | | | Full range | | | 200 | |
| SR | Slew rate | $V_{CC} = \pm 15\text{ V}$, $C_L = 100\text{ pF}$, $V_I = \pm 10\text{ V}$, $R_L = 10\text{ k}\Omega$ | 25°C | 1.3 | 2 | | V/ μs |
| GBW | Gain bandwidth product | $R_L = 10\text{ k}\Omega$, $C_L = 100\text{ pF}$, $f = 100\text{ kHz}$ | 25°C | 1.4 | 2.1 | | MHz |
| Φ_m | Phase margin | $R_L = 10\text{ k}\Omega$, $C_L = 100\text{ pF}$ | 25°C | | 45 | | ° |
| THD | Total harmonic distortion | | 25°C | | 0.01 | | % |
| V_n | Equivalent input noise voltage | $f = 1\text{ kHz}$ | 25°C | | 19 | | $\text{nV}/\sqrt{\text{Hz}}$ |

TSM102, TSM102A DUAL OPERATIONAL AMPLIFIER, DUAL COMPARATOR, AND VOLTAGE REFERENCE

SLVS602–MARCH 2006

Comparator Electrical Characteristics

$V_{CC+} = 5\text{ V}$, $V_{CC-} = \text{GND}$ (unless otherwise noted)

| PARAMETER | TEST CONDITIONS | T_A | MIN | TYP | MAX | UNIT |
|-------------------------|---------------------------------------|---|------------|-----|-----------------|---------------|
| V_{IO} | Input offset voltage | 25°C | | | 5 | mV |
| | | Full range | | | 9 | |
| V_{ID} | Comparator differential input voltage | Full range | | | V_{CC+} | V |
| I_{IO} | Input offset current | 25°C | | | 50 | nA |
| | | Full range | | | 150 | |
| I_{IB} | Input bias current | 25°C | | | 250 | nA |
| | | Full range | | | 400 | |
| I_{OH} | High-level output current | $V_{ID} = 1\text{ V}$, $V_{CC} = V_O = 30\text{ V}$ | | 0.1 | | nA |
| | | Full range | | | 1 | μA |
| V_{OL} | Low-level output voltage | $V_{ID} = -1\text{ V}$, $I_{\text{sink}} = 4\text{ mA}$ | | 250 | 400 | mV |
| | | Full range | | | 700 | |
| A_{VD} | Large-signal voltage gain | $V_{CC+} = 15\text{ V}$, $R_1 = 15\text{ k}\Omega$, $V_O = 1\text{ V to }11\text{ V}$ | | 200 | | V/mV |
| I_{sink} | Output sink current | $V_O = 1.5\text{ V}$, $V_{ID} = -1\text{ V}$ | 25°C | 6 | 16 | mA |
| V_{ICM} | Input common-mode voltage range | | 25°C | 0 | $V_{CC+} - 1.5$ | V |
| | | | Full range | 0 | $V_{CC+} - 2$ | |
| t_{RESP} | Response time ⁽¹⁾ | $R_1 = 5.1\text{ k}\Omega$ to V_{CC+} , $V_{\text{REF}} = 1.4\text{ V}$ | 25°C | | 1.3 | μs |
| $t_{\text{RESP,large}}$ | Large-signal response time | $R_1 = 5.1\text{ k}\Omega$ to V_{CC+} , $V_{\text{REF}} = 1.4\text{ V}$, $V_I = \text{TTL}$ | 25°C | | 300 | ns |

(1) The response-time specification is for 100-mV input step with 5-mV overdrive. For larger overdrive signals, 300 ns can be obtained.

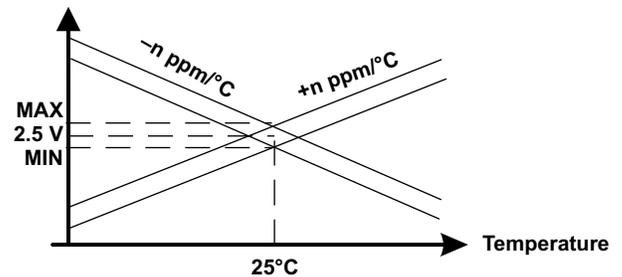
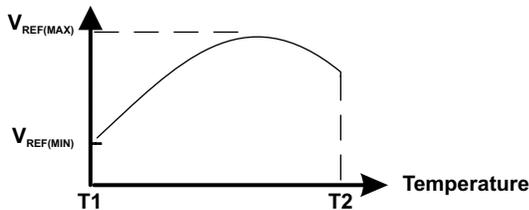
Voltage-Reference Electrical Characteristics

| PARAMETER | | TEST CONDITIONS | T _A | MIN | TYP | MAX | UNIT |
|--------------------------|---|--|----------------|-------|------|-------|--------|
| V _{REF} | Reference voltage ⁽¹⁾ | V _{KA} = V _{REF} , I _K = 10 mA, See Figure 1 | 25°C | 2.475 | 2.5 | 2.525 | V |
| | | | 25°C | 2.49 | 2.5 | 2.51 | |
| ΔV _{REF} | Reference input voltage deviation over temperature range ⁽¹⁾ | V _{KA} = V _{REF} , I _K = 10 mA, See Figure 1 | Full range | | 7 | 30 | mV |
| $\frac{V_{REF}}{T}$ | Average temperature coefficient of reference input voltage ⁽²⁾ | V _{KA} = V _{REF} , I _K = 10 mA | Full range | | ±22 | ±100 | ppm/°C |
| $\frac{V_{REF}}{V_{KA}}$ | Ratio of change in reference voltage to change in cathode voltage | V _{KA} = 3 V to 36 V, I _K = 10 mA, See Figure 2 | 25°C | | -1.1 | -2 | mV/V |
| I _{REF} | Reference input current | I _K = 10 mA, R1 = 10 kΩ, R2 = ∞, See Figure 2 | 25°C | | 1.5 | 2.5 | μA |
| | | | Full range | | | 3 | |
| ΔI _{REF} | Reference input current deviation over temperature range | I _K = 10 mA, R1 = 10 kΩ, R2 = ∞, See Figure 2 | Full range | | 0.5 | 1 | μA |
| I _{min} | Minimum cathode current for regulation | V _{KA} = V _{REF} , See Figure 1 | 25°C | | 0.5 | 1 | mA |
| I _{K,OFF} | Off-state cathode current | See Figure 3 | 25°C | | 180 | 500 | nA |

(1) ΔV_{REF} is defined as the difference between the maximum and minimum values obtained over the full temperature range.

$$\Delta V_{REF} = V_{REF(MAX)} - V_{REF(MIN)}$$

(2) The temperature coefficient is defined as the slopes (positive and negative) of the voltage vs temperature limits within which the reference voltage is specified.



PARAMETER MEASUREMENT INFORMATION

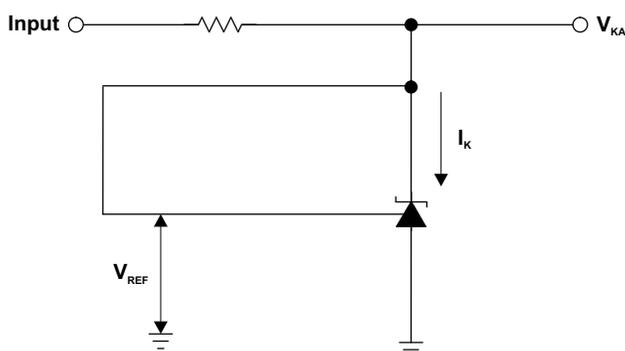


Figure 1. Test Circuit for $V_{KA} = V_{REF}$

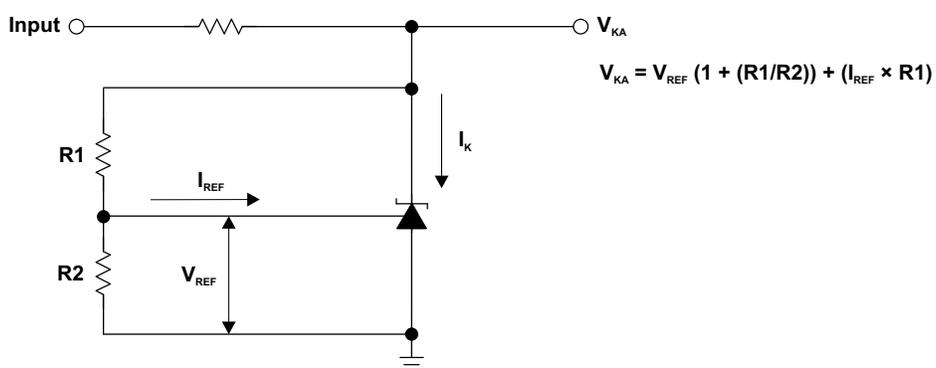


Figure 2. Test Circuit for $V_{KA} > V_{REF}$

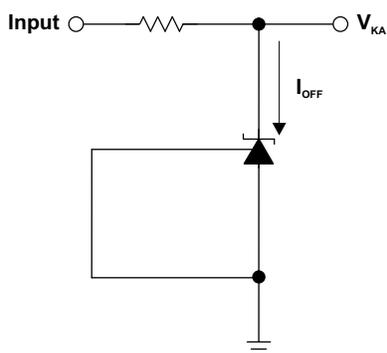


Figure 3. Test Circuit for I_{OFF}

TYPICAL CHARACTERISTICS

**AMPLIFIER TOTAL HARMONIC DISTORTION
VS
FREQUENCY**

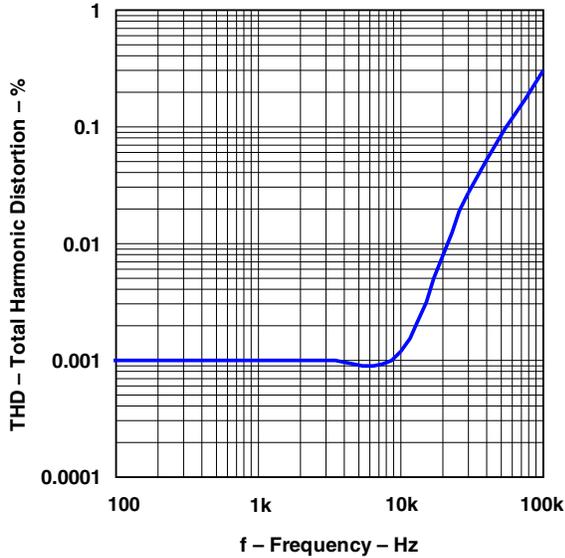


Figure 4.

**AMPLIFIER NOISE VOLTAGE
VS
FREQUENCY**

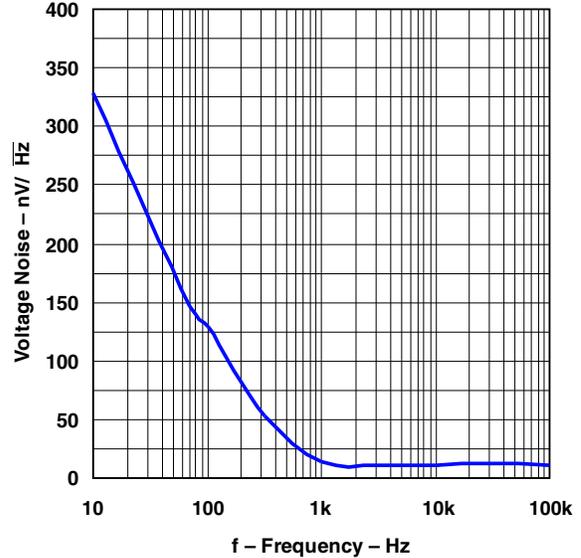


Figure 5.

**GAIN AND PHASE
VS
FREQUENCY**

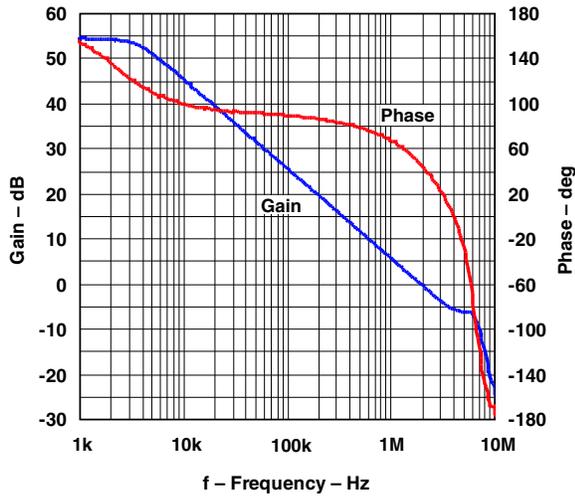


Figure 6.

**V_{REF} STABILITY
VS
CAPACITANCE**

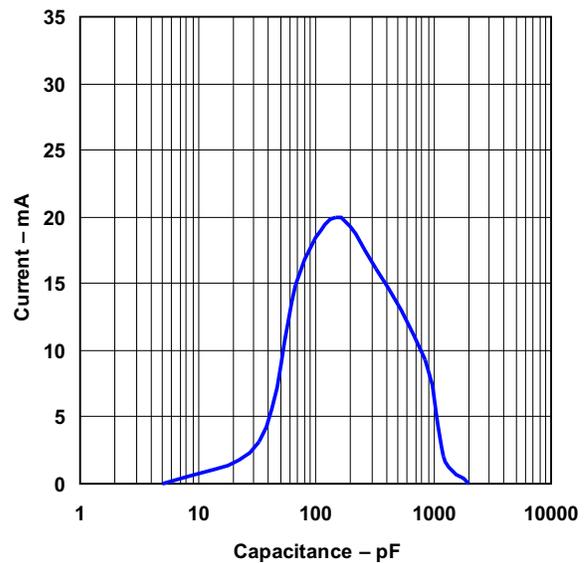


Figure 7.

TYPICAL CHARACTERISTICS (continued)

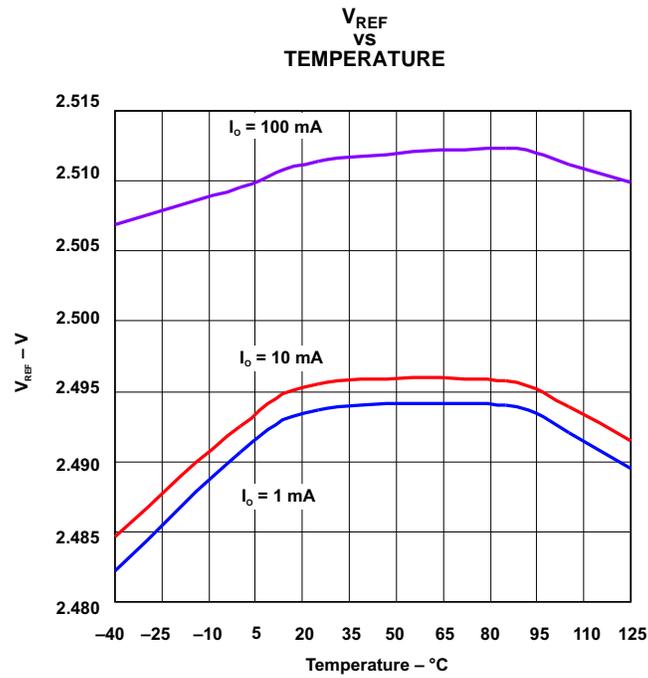


Figure 8.

PACKAGING INFORMATION

| Orderable Device | Status ⁽¹⁾ | Package Type | Package Drawing | Pins | Package Qty | Eco Plan ⁽²⁾ | Lead/Ball Finish | MSL Peak Temp ⁽³⁾ |
|------------------|-----------------------|--------------|-----------------|------|-------------|-------------------------|------------------|------------------------------|
| TSM102AID | ACTIVE | SOIC | D | 16 | 40 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| TSM102AIDR | ACTIVE | SOIC | D | 16 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| TSM102AIPW | ACTIVE | TSSOP | PW | 16 | 90 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| TSM102AIPWR | ACTIVE | TSSOP | PW | 16 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| TSM102ID | ACTIVE | SOIC | D | 16 | 40 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| TSM102IDR | ACTIVE | SOIC | D | 16 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| TSM102IPW | ACTIVE | TSSOP | PW | 16 | 90 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| TSM102IPWR | ACTIVE | TSSOP | PW | 16 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

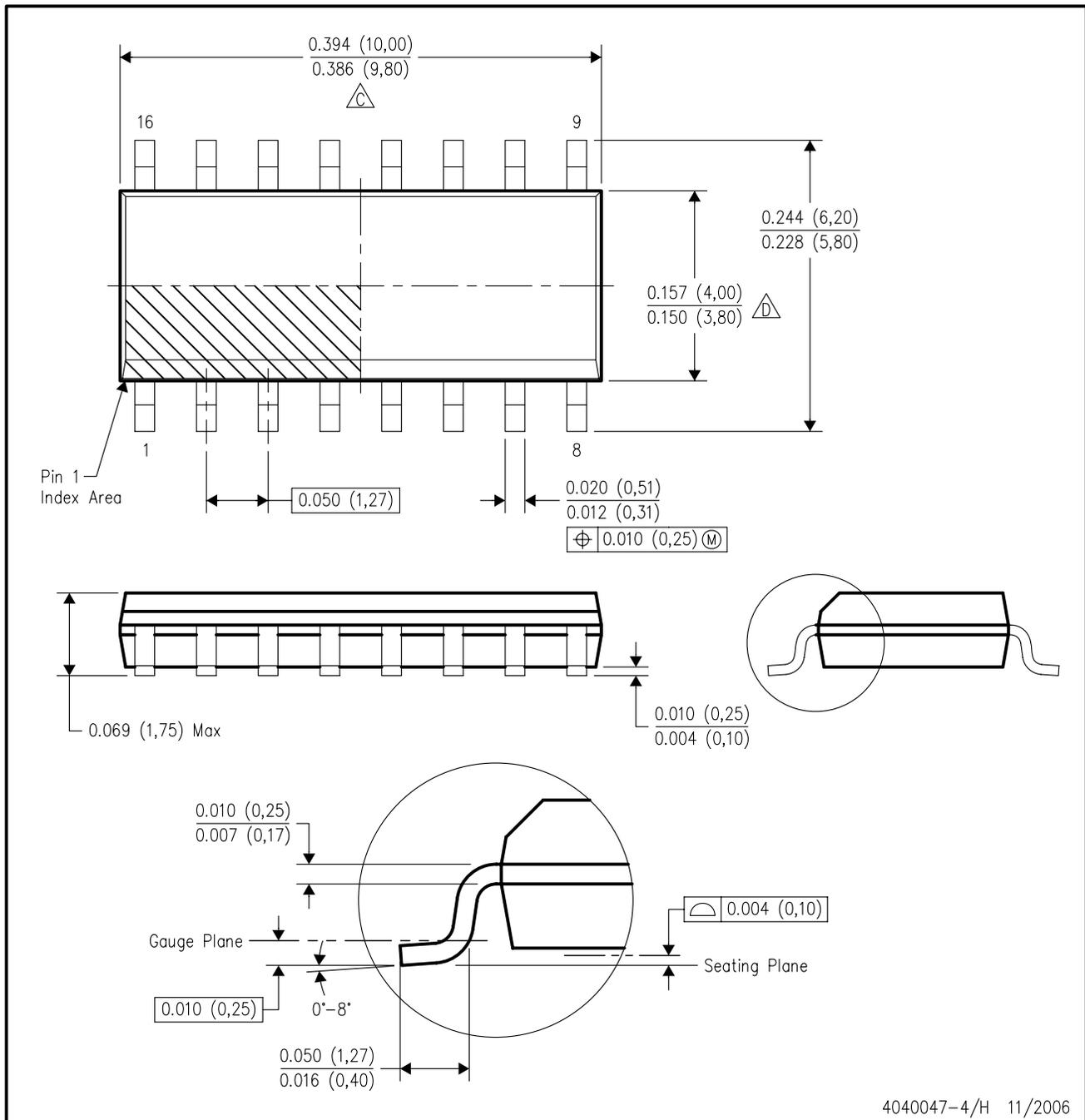
⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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D (R-PDSO-G16)

PLASTIC SMALL-OUTLINE PACKAGE

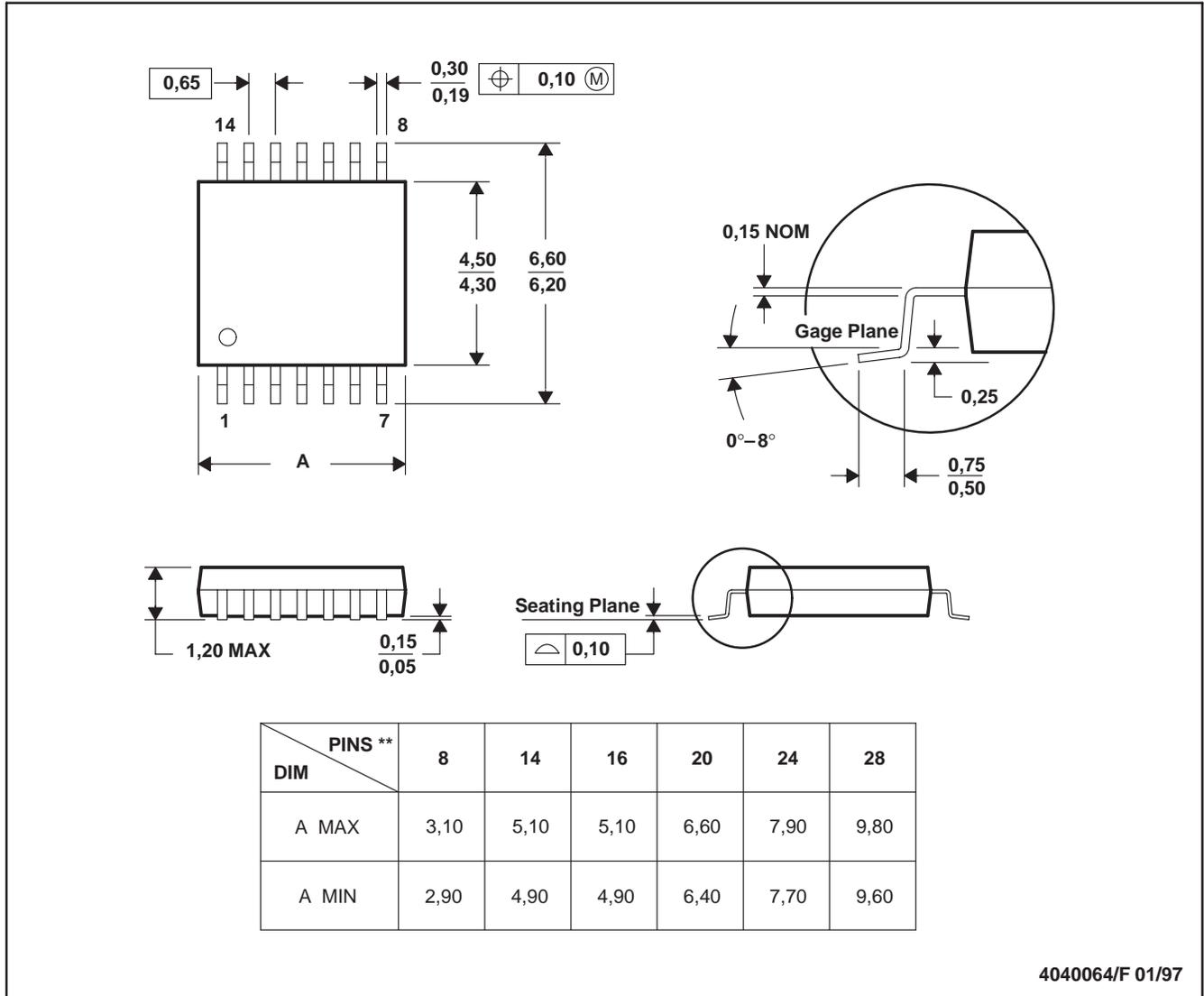


- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.
 - D. Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.
 - E. Reference JEDEC MS-012 variation AC.

PW (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

14 PINS SHOWN



4040064/F 01/97

- NOTES: A. All linear dimensions are in millimeters.
 B. This drawing is subject to change without notice.
 C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
 D. Falls within JEDEC MO-153

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